TOSHIBA Photocoupler Photorelay

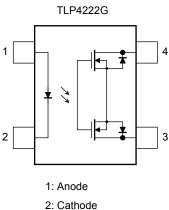
# TLP4222G,TLP4222G-2

**Telecommunication** Measurement Equipment Security Equipment FA

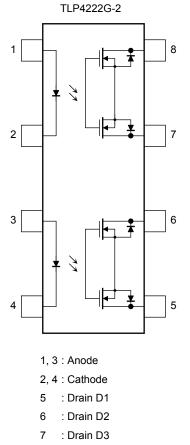
The Toshiba TLP4222G consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET and is the normally closed photorelay with 350-V withstanding voltage.

- Normally closed device •
- Peak off-state voltage: 350 V (min) •
- Trigger LED current: 3 mA (max)
- On-state current: 100 mA (max) •
- On-state resistance: 50  $\Omega$  (max) .
- Isolation voltage: 2500 Vrms (min)
- UL Recognized: UL1577, File No. E67349

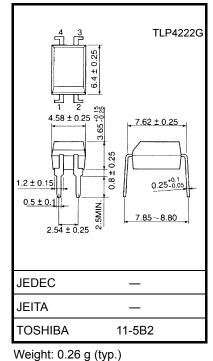
# **Pin Configuration (top view)**

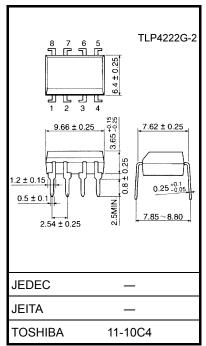


- 3: Drain
- 4: Drain



: Drain D4 8





Weight: 0.54 g (typ.)

Unit: mm

Absolute Maximum Ratings (Ta = 25°C)

	Characteristics				Rating	Unit
	Forward current	١ <sub>F</sub>	50	mA		
	Forward current derating (Ta ≧	∆I <sub>F</sub> /°C	-0.5	mA/°C		
LED	Peak forward current (100 µs p	oulse, 100 pps)		I <sub>FP</sub>	1	А
	Reverse voltage			V <sub>R</sub>	5	V
	Junction temperature	Tj	125	°C		
	Off-state output terminal voltag	V <sub>OFF</sub>	350	V		
	On-state current	TLP4222G				
		TLP4222G-2	One channel operation	I <sub>ON</sub>	100	mA
Detector		1LF4222G-2	Two channel operations			
Dete	On-state current derating (Ta ≧ 25°C)	TLP4222G				
		TLP4222G-2	One channel operation	∆l <sub>ON</sub> /°C	-1.0	mA/°C
	, , , , , , , , , , , , , , , , , , ,	1LF4222G-2	Two channel operations			
	Junction temperature		Tj	125	°C	
Stora	age temperature range	T <sub>stg</sub>	-55 to 125	°C		
Oper	rating temperature range	T <sub>opr</sub>	-40 to 85	°C		
Lead	I soldering temperature (10 s)	T <sub>sol</sub>	260	°C		
Isola	tion voltage (AC, 1 min, R.H. $\leq$	BVS	2500	Vrms		

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: For TLP4222G, Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together. For TLP4222G-2, Pins 1, 2, 3 and 4 are shorted together, and pins 5, 6, 7 and 8 are shorted together.

#### **Recommended Operating Conditions**

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V <sub>DD</sub>			280	V
Forward current	١ <sub>F</sub>	5		25	mA
On-state current	I <sub>ON</sub>	_	_	100	mA
Operating temperature	T <sub>opr</sub>	-20		65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

#### **Electrical Characteristics (Ta = 25°C)**

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
LED	Forward voltage	VF	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
	Reverse current	Ι <sub>R</sub>	$V_R = 5 V$	_	_	10	μA
	Capacitance	CT	V = 0, f = 1 MHz	_	30	_	pF
Detector	Off-state current	I <sub>OFF</sub>	$V_{OFF} = 350 \text{ V}, \text{ I}_F = 5 \text{ mA}$	_	_	1	μA
	Capacitance	C <sub>OFF</sub>	$V=0,f=1\;MHz,I_F=5\;mA$		30	_	pF

# **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I <sub>FC</sub>	I <sub>OFF</sub> = 10 μA	_	1	3	mA
Return LED current	I <sub>FT</sub>	I <sub>ON</sub> = 100 mA	0.1	_		mA
On-state resistance	R <sub>ON</sub>	I <sub>ON</sub> = 100 mA		27	50	Ω

## **Isolation Characteristics (Ta = 25°C)**

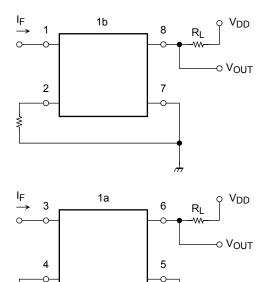
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	$V_S = 0, f = 1 MHz$	_	0.8	_	pF
Isolation resistance	R <sub>S</sub>	$V_S = 500 \text{ V}, \text{ R.H.} \leq 60\%$	$5\times10^{10}$	10 <sup>14</sup>	_	Ω
	BVS	AC, 1 min	2500	_	_	Vrms
Isolation voltage		AC, 1 s, in oil		5000	_	
		DC, 1 min, in oil	—	5000	_	Vdc

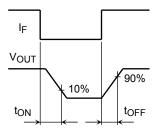
### Switching Characteristics (Ta = 25°C)

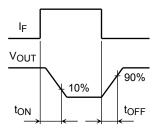
Characteristics	Symbol	Test Condition		Min	Тур.	Max	Unit
Turn-on time	t <sub>ON</sub>	R <sub>L</sub> = 200 Ω		_	0.25	0.5	ms
Turn-off time	t <sub>OFF</sub>	$V_{DD} = 20 \text{ V}, \text{ I}_{\text{F}} = 5 \text{ mA}$ (No	(Note 2)	—	0.5	1	ms

Note 2: Switching time test circuit

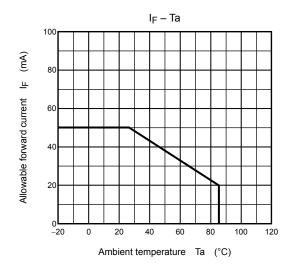
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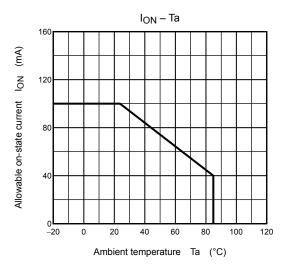


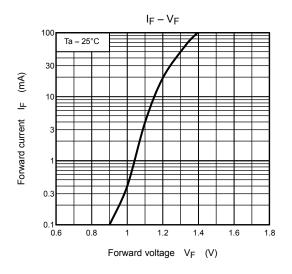




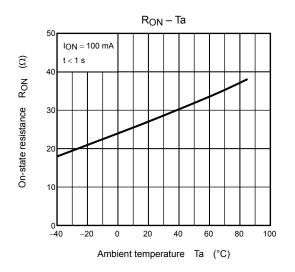
# **TOSHIBA**

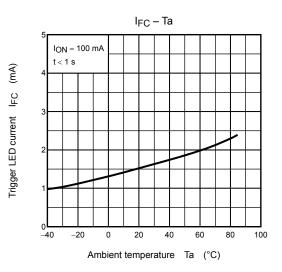


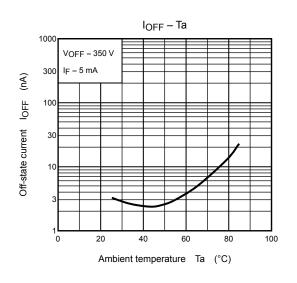


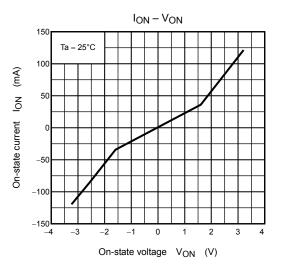


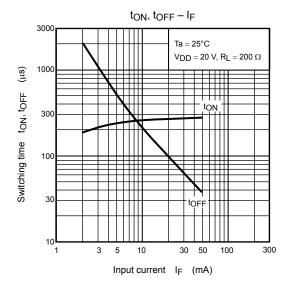
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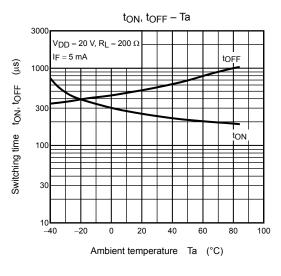












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